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ARTICLE

Fabrication of g-C₃N₄/MoS₂ Nanosheet Heterojunction by Facile Ball Milling Method and Its Visible Light Photocatalytic Performance

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Abstract: The g-C₃N₄/MoS₂ nanosheet heterojunction was prepared via a facile ball milling method. The microstructure and morphology of the composite were characterized by X-ray diffraction (XRD), high-resolution transmission electron microscopy (HRTEM), UV-vis diffuse reflectance spectroscopy (DRS) and photoluminescence (PL) spectroscopy. The photocatalytic activities were evaluated by the degradation of organic Rhodamine B (RhB) under visible light irradiation. The results indicate that MoS₂ nanosheets are successfully coupled into g-C₃N₄ to form a C₃N₄/MoS₂ heterojunction. The kinetic constant of RhB degradation with g-C₃N₄/MoS₂ nanosheets-2 wt% heterojunction (0.0368 min⁻¹) is about 4.3 times as high as that of the bulk g-C₃N₄ (0.00840 min⁻¹). The enhanced photocatalytic activities can be mainly ascribed to the efficient separation and transportation of photo-induced electron-hole pairs. The possible photocatalytic mechanism of composites was proposed according to the light trapping experiment.

Key words: MoS₂ nanosheets; graphite phase carbon nitride; heterojunction; ball milling; visible light photocatalysis

Semiconductor photocatalysis has been developed as a kind of green technology for controlling environmental pollutants because of their semiconducting characteristics and commercial availability^[1,2]. Many semiconductor materials, such as TiO₂, WO₃, CdS, ZnS and ZnO, have been investigated as photocatalysts for the degradation of organic compounds^[3-7]. However, various shortcomings, such as low utilization of visible light and high recombination rate of the photo-generated electron-hole pairs greatly restrict the efficiency of these photocatalysts. Therefore, it has become a hot issue in photocatalysis field to explore more efficient visible light catalysts for meeting the requirement of practical applications.

Recently, the graphite phase carbon nitride $(g-C_3N_4)$ have attracted much attention in hydrogen production by water splitting and degradation of pollutants under visible light

irradiation^[8-11]. The g-C₃N₄ has many advantages such as good chemical stability, a band gap of 2.7 eV as well as layered structure. Nevertheless, the photocatalytic performance of bulk g-C₃N₄ is limited due to the fast recombination of photo-generated electron-hole pairs and a small specific surface area. More studies have showed that the g-C₃N₄-based heterojunction structure can obviously increase the photocatalytic efficiency by improving the electron-hole pair separation efficiency^[12-16]. MoS₂ nanosheets have many unique optical and electrical properties compared with its bulk structure. MoS₂ nanosheets can construct the semiconductor heterojunction with g-C₃N₄ due to a suitable band gap of 1.9 eV, large specific surface area and more unsaturated bonds on the surface of MoS₂ nanosheets^[17-25]. Lu et al^[26] used a bathing and ultrasound method to prepare graphitic C3N4/ultrathin MoS_2 hybrids for organic degradation, which accelerate the

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separation of photo-generated electron-hole pairs. Hou et al^[27] constructed a porous $g-C_3N_4$ nanosheets, N-doped graphene, and layered MoS₂ ternary heterojunction by a hydrothermal method. The ternary heterojunction shows significantly enhanced photocatalytic activities owing to the large specific surface area, enhanced visible light absorption, and fast electron-hole pair separation and transfer. However, in these works, $g-C_3N_4/MoS_2$ photocatalyst heterojunction was synthesized at high temperature or by a complicate synthesis process. It is still necessary to explore a facile, low energy consumption and effective methods to obtain $g-C_3N_4/MoS_2$ heterojunction composites with high photocatalytic efficiency.

In this study, the $g-C_3N_4/MoS_2$ nanosheet heterojunction photocatalysts were prepared by a ball milling method. Compared with other composite preparation methods, ball milling is a simple and mass preparation technique to synthesize composite photocatalysts. The resultant composite photocatalysts exhibited enhanced visible light photocatalytic activities by RhB degradation. A possible photocatalytic mechanism of the composite photocatalysts was also proposed.

1 Experiment

The bulk g-C₃N₄ (BCN) powder was synthesized by directly heating melamine according to a reported method^[8]. 10 g melamine powder was heated to 520 °C in a muffle furnace with a rate of 5 °C/min for 4 h. After the reaction, the resultant g-C₃N₄ was collected and ground into powders for further use.

 MoS_2 nanosheets (MSNs) were prepared by a two-step procedure in modified methods 6 the Ref. [28]. Firstly, 2 g of MoS_2 powder was dispersed in 200 mL N-methyl-2-pyrrolidone (NMP) and the mixture was put in a sealed polypropylene bottle with 500 zirconia balls. The milling speed was set to 100 r/min. The milling time was 24 h. Secondly, the samples were further subjected to ultrasonic treatment at low power output (100 W) for 2 h. Then layered MoS_2 nanosheets were prepared in NMP solutions.

The preparation of g-C₃N₄/MoS₂ nanosheet heterojunction photocatalyst was achieved in QM-3SP04 ball mill. The details of the procedure were as follows: the g-C₃N₄ powders were put together with a certain amount of MoS₂ nanosheet solutions, and then the agate balls were mixed in the agate jar at a mass ratio of 1:10. After milling at a speed of 400 r/min for 4 h, the final products were washed and dried in a vacuum oven at 80 °C for 10 h. The obtained g-C₃N₄/MoS₂ nanosheet heterojunction photocatalyst with different MoS₂ mass fractions of 0.5%, 1%, 2% and 3% were donated as BCNMSNs-0.5, BCNMSNs-1, BCNMSNs-2 and BCNMSNs-3, respectively. The sample named M-BCNMSNs-2 (2 wt% MoS₂) was obtained by directly mixing the MoS₂ nanosheets with g-C₃N₄.

The crystalline phases of the samples were analyzed by X-ray diffraction (XRD, Bruker D8 Advance X-ray diffractometer)

with Cu K α radiation source. The morphologies of the samples were characterized by transmission electron microscopy (TEM, Tecnai G20). The UV-vis diffuse reflectance spectra (UV-vis DRS) were obtained by UV-vis spectrophotometer (Shimadzu, UV-3600) with BaSO₄ as a reflectance standard. The photoluminescence spectra were obtained on a HORIBA Fluorolog-3 type fluorescence spectrophotometer with an excitation wavelength of 270 nm.

The photocatalytic performance of the samples was evaluated by the degradation of the organic RhB by a 300 W Xe lamp with a cutoff filter (λ >420 nm). In a typical photocatalytic experiment, 20 mg of photocatalyst was added into 100 mL of the RhB solution (20 mg/L), and then the solution was stirred in the dark for 30 min to establish an adsorption-desorption equilibrium before visible light irradiation. Next, 3 mL of the solution was collected at a given time interval, and then centrifuged (10 000 r/min, 5 min) to remove the particles. The concentration of RhB was determined at the 553 nm absorbance value.

The trapping experiments were performed according to the Ref. [29-31]. 0.1 mL of isopropanol (IPA), 0.1 g of benzoquinone (BQ) and 0.1 g of ammonium oxalate (AO) were added to the RhB solution for photocatalytic degradation.

2 Results and Discussion

2.1 Crystallization phase structure and morphology of the composite photocatalysts

Fig.1 depicts the XRD patterns of bulk $g-C_3N_4$, MoS_2 nanosheets and $g-C_3N_4$ / MoS_2 nanosheet heterojunctions with different MoS_2 contents. There are two distinct peaks (27.5° and 13.1°) in bulk $g-C_3N_4$. It can be indexed as the (002) and (100) diffraction planes of the $g-C_3N_4$ (JCPDS 87-1526). The strong peak at 27.5° is related to the inter-layer stacking of aromatic systems and the weak peak at 13.1° corresponds to the in-plane structural packing motif. Moreover, the peak of MoS_2 nanosheets at 14.3°, 32.6°, 33.4°, 35.8°, 39.4°, 44.1°, 58.2° and 60.2° are assigned to the hexagonal structure of MoS_2 (JCPDS No.37-1492). The diffraction peaks indicate that the MoS_2 nanosheets still keep well crystallinity after ball



Fig.1 XRD patterns of BCN, MSNs, M-BCNMSNs-2 and BCN-MSNs-2

milling and ultrasonic exfoliation. The diffraction peak positions of the M-BCNMSNs and BCN-MSNs samples are similar to those of $g-C_3N_4$. The results indicate that MoS_2 nanosheets do not incorporate into the $g-C_3N_4$ lattice. There are no apparent peaks of MoS_2 in the M-BCNMSNs and BCN-MSNs, because the MoS_2 content is lower.

Fig.2a shows a high-resolution TEM image of MoS_2 nanosheets. The MoS_2 nanosheets consist of several atomic layers (3 layer). The lattice spacing (d=0.62 nm) corresponds to the (002) plane of MoS_2 . Fig.2b shows the TEM image of the g-C₃N₄/MoS₂ nanosheets-2% composite. The MoS_2 nanosheets are inserted onto the layered structure of the g-C₃N₄. The selected region marked by the white circle in Fig.2b is magnified to investigate the fine structure of the g-C₃N₄/MoS₂ nanosheets-2% composite (Fig.2c). The magnified TEM image shows the formation of MoS_2 nanosheets/g-C₃N₄ heterojunction with intimate interfacial contact.In particular , the bulk g-C₃N₄ can be exfoliated during the ball milling and ultrasonic procedure.

2.2 DRS and PL analyses

The UV-vis diffuse reflectance spectra of bulk $g-C_3N_4$ and $g-C_3N_4/MoS_2$ nanosheets with different MoS_2 contents are shown in Fig.3. The bulk $g-C_3N_4$ sample displays absorption from the ultraviolet to the visible range up to 460 nm, which can be ascribed to the small band gap of bulk $g-C_3N_4$. The

M-BCNMSNs-2 sample shows the same absorption edge as bulk g-C₃N₄, indicating that MoS₂ nanosheets do not influence g-C₃N₄ structure through the simple physical mixing method. However, compared with bulk g-C₃N₄, the absorption edge of the BCN-MSNs sample presents a red shift. At the same time, the absorption peak intensity above 450 nm is enhanced with increasing MoS₂ contents. The results imply that MoS₂ nanosheets are successfully coupled into g-C₃N₄ to form a g-C₃N₄/MoS₂ heterojunction by ball mill process. Therefore, the g-C₃N₄/MoS₂ heterojunction can capture more visible light and enhance catalytic activity.

The separation and recombination of photogenerated electron-hole pairs is very important to the performance of the catalyst. The photoluminescence spectra can be used to reveal the separation and recombination of photogenerated charges in semiconductor materials. Fig.4 shows the PL spectra of bulk g-C₃N₄ and g-C₃N₄/MoS₂ nanosheets with different MoS₂ contents. The bulk g-C₃N₄ has a strong fluorescence emission peak near 465 nm, which is consistent with the absorption boundary of g-C₃N₄ in the UV-Vis spectrum^[32]. The results show that the photogenerated electron-hole pairs are easy to combine in bulk g-C₃N₄, which is not conducive to its photocatalytic performance. The mechanical mixture of g-C₃N₄/MoS₂ nanosheets shows high PL emission intensity, which means that the sample still maintains a higher recombination



Fig.2 HR-TEM images of MSNs (a), TEM image of BCN-MSNs-2 (b), and HR-TEM image of marked region in Fig.2b (c)



Fig.3 UV-vis diffuse reflectance spectra of different samples



Fig.4 PL spectra of different samples with an excitation wavelength of 270 nm

rate of photo-generated charges. The intensities of PL spectra for $g-C_3N_4/MoS_2$ nanosheets composites decrease with increasing MoS_2 content, which indicates that the separation efficiency of photo-induced charges in the composites is obviously improved.

2.3 Photocatalytic activities analyses

The photocatalytic activities of the different samples were evaluated by the degradation of RhB under visible light irradiation, as shown in Fig.5. The RhB is degraded by nearly 3.2% at 120 min without catalyst, suggesting that the effect of self-photo degradation for RhB is limited. The bulk g-C₃N₄ sample shows visible light photocatalytic activity. After 120 min of visible light illumination, the RhB has been degraded by about 63%. The mechanical mixture $g-C_3N_4/MoS_2$ nanosheets only degrades 70% of RhB after 120 min of visible light illumination. The results show that only simple mechanical mixing of MoS₂ nanosheets with g-C₃N₄ cannot improve photocatalytic performance of bulk g-C₃N₄. Compared with the bulk g-C₃N₄ and the mechanical mixture of g-C₃N₄/MoS₂ nanosheets, the g-C₃N₄/MoS₂ nanosheet composite catalyst exhibits excellent photocatalytic activity. The BCNMNs-2 composites result in a 98% degradation of RhB within 120 min. For low concentration pollutants, the kinetics behaviors for the degradation reaction can be studied by the equation:

$$\ln\left(C/C_0\right) = kt\tag{1}$$

where *C* is the concentration of the pollutant degradated by photocatalyst (mg·L⁻¹), C_0 is the adsorption equilibrium concentration of the pollutant before irradiation (mg·L⁻¹), *t* is the reaction time (min), and *k* is the kinetic constant (min⁻¹). The kinetic constants (*k*) of different samples are calculated and shown in Fig.6. The kinetic constant of RhB degradation with BCNMSNs-2 (0.0368 min⁻¹) is about 4.3 and 3.8 times as high as that of the BCN (0.008 40 min⁻¹) and M-BCNMSNs-2 (0.009 69 min⁻¹), respectively. The results show that the formation of MoS₂ nanosheets/g-C₃N₄ heterojunction can efficiently enhance the photocatalytic peformance of g -C₃N₄.



Fig.5 Photocatalytic degradation of RhB as a function of irradiation time for different samples under visible light irradiation



Fig.6 Kinetic plots of photocatalytic degradation of RhB for different samples under visible light irradiation

2.4 Photocatalytic mechanism of MoS₂ nanosheets/g-C₃N₄ heterojunction

To investigate the photocatalytic mechanism of the g-C₃N₄/ MoS_2 nanosheet heterojunction with 2 wt% MoS_2 , the trapping experiments of the photocatalysts were carried out for determining the main active species. The scavengers used in this study are AO for holes (h^+) , IPA for hydroxyl radicals (•OH) and BQ for superoxide radicals ($\bullet O_2$ -). The results are shown in Fig.7. The degradation rate (η) of RhB obviously decreases with the addition of AO compared to the use of IPA and BQ. It manifests that holes play a main role in the RhB degradation process, while hydroxyl radicals and superoxide radicals can be negligible in the reaction. According to the above results, the possible mechanism of the g-C₃N₄/MoS₂ nanosheet heterojunction is illustrated in Fig.8. The electrons from the valence bands (VBs) of g-C₃N₄ and MoS₂ nanosheets are excited to their respective conduction bands (CBs) under the visible light irradiation, which simultaneously create holes in the VB. The CB and VB edge potentials of the bulk g-C₃N₄ are -1.13 eV and +1.57 eV, respectively^[33]. The CB and VB edge potentials of MoS₂ nanosheets are -0.12 eV and +1.78 eV^[34], respectively. The CB and VB edge potentials of MoS₂ nanosheets are more positive than that of g-C₃N₄. Therefore, the photo-induced electrons from the CB of g-C₃N₄ particle move to the CB of MoS₂ nanosheets through heterojunction interface in this sample. As reported^[26,35], the MoS₂ nanosheets show higher electron mobility than bulk MoS₂, which is beneficial to the transferring photogenerated charges. At the same time, the holes in the VB of the MoS₂ nanosheets can be transferred to the $g-C_3N_4$ by the internal static electric fields. Consequently, the electrons are gathered in the CB of the MoS₂ and the holes in the VB of the g-C₃N₄. However, the electrons in the CB of the MoS_2 (-0.12 eV) cannot reduce O_2 to yield •O₂- (E (O₂/•O₂-) = -0.33 eV)^[36], and the holes in the VB of the g-C₃N₄ (+1.57 eV) cannot oxidize H₂O to give •OH (E $(\bullet OH/H_2O) = 2.27 \text{ eV})^{[37]}$. As a result, the holes in the VB of the g-C₃N₄ as the main reactive species can degrade the RhB



Fig.7 Degradation efficiency (η) of RhB in presence of different scavengers under visible light irradiation



Fig.8 Schematic diagram of the photocatalytic degradation and charge transfer mechanism in the MoS_2 nanosheet/g-C₃N₄ heterojunction systems

molecules, which is consistent with the result of adding scavengers. The results are in good agreement with the reported results of Li et al ^[25].

3 Conclusions

1) The MoS_2 nanosheets/g-C₃N₄ heterojunction can be prepared by a facile ball milling method.

2) The heterojunction shows significantly enhanced photocatalytic performance for the degradation of RhB under visible light irradiation.

3) The enhanced photocatalytic activity is mainly attributed to the efficient separation and transport of photoinduced electron-hole pairs in the heterojunction structure.

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g-C₃N₄/MoS₂纳米片异质复合物的球磨法制备及可见光催化性能

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摘 要:采用球磨法制备 g-C₃N₄/MoS₂纳米片异质复合物,运用 X 射线衍射仪、高分辨率透射电镜、紫外可见漫反射光谱和荧光发射光 谱对异质复合物的结构和形貌进行了表征。以罗丹明 B 为模拟污染物,在可见光照射下考察了复合物的光催化特性。结果表明: MoS₂ 纳米片可进入g-C₃N₄的层间形成异质复合物。含有 2% MoS₂纳米片与g-C₃N₄形成的异质复合物在 120 min 内对罗丹明 B 的降解率为 98%, 其降解动力学常数是体相 g-C₃N₄的 4.3 倍。g-C₃N₄/MoS₂纳米片异质复合物具有十分优良的光催化特性,其催化活性的提高主要归因于 光生电子和空穴的有效分离和传输。根据光捕获实验提出了复合物可能的光催化机理。

关键词: MoS₂纳米片; 石墨相氮化碳; 异质复合物; 球磨; 可见光催化

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